

Photocouplers Infrared LED & Photo Darlington Transistor

TLP627M,TLP627MF

1. Applications

- · Programmable Logic Controllers (PLCs)
- I/O Interface Boards
- · Home Electric Appliances

2. General

TLP627M is a photocoupler that consists of an infrared emitting diode optically coupled to a photo darlington transistor. Housed in a 4pin DIP, it has a high noise immunity and high insulation. With the high breakdown voltage between the collector and emitter, TLP627M is suitable in applications such as 100 V DC output modules of programmable controllers.

TLP627MF is a lead forming type for the long creepage mounting of TLP627M.

3. Features

- (1) Collector-emitter voltage: 300 V (min)
- (2) Current transfer ratio: 1000 % (min) (@I_F = 1 mA, V_{CE} = 1 V)
- (3) Isolation voltage: 5000 Vrms (min)
- (4) Operating temperature: -55 to 110 °C
- (5) Safety standards

UL-recognized: UL 1577, File No.E67349

cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN IEC 60747-5-5, EN IEC 62368-1 (Note 1)

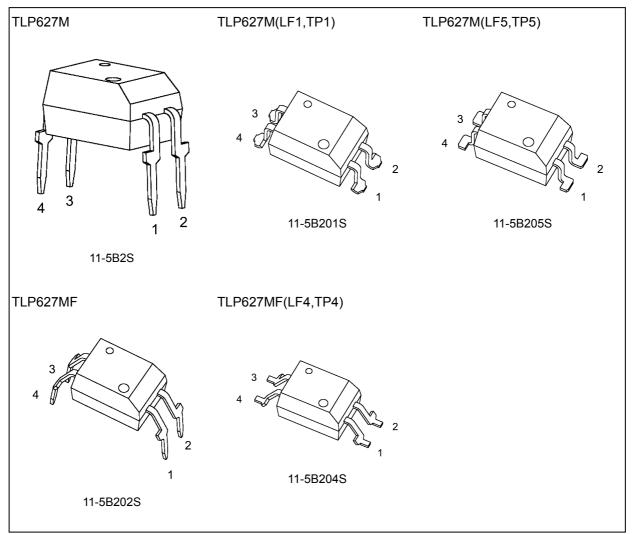
CQC-approved: GB4943.1 Japan Factory



Note 1: When a VDE approved type is needed, please designate the Option (D4).

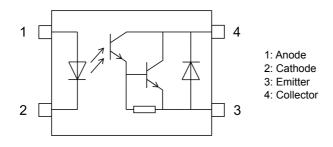


4. Packaging (Note)



Note: Through-hole type: TLP627M, TLP627MF Lead forming option: (LF1), (LF4), (LF5) Taping option: (TP1), (TP4), (TP5)

5. Pin Assignment



6. Mechanical Parameters

Characteristics	7.62 mm pitch TLP627M type (Min)	10.16 mm pitch TLP627MF type (Min)	Unit
Creepage distances	7.0	8.0	mm
Clearance	7.0	8.0	
Internal isolation thickness	0.4	0.4	



7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		50	mA
	Input forward current derating	(T _a ≥ 90 °C)	$\Delta I_F / \Delta T_a$		-1.42	mA/°C
	Input forward current (pulsed)		I _{FP}	(Note 1)	1	Α
	Input reverse voltage		V_{R}		5	V
	Input power dissipation		P_{D}		100	mW
	Input power dissipation derating	(T _a ≥ 90 °C)	$\Delta P_D/\Delta T_a$		-2.85	mW/°C
	Junction temperature		Tj		125	°C
Detector	Collector-emitter voltage		V_{CEO}		300	V
	Emitter-collector voltage		V _{ECO}		0.3	V
	Collector current		Ic		150	mA
	Collector power dissipation		P _C		150	mW
	Collector power dissipation derating	(T _a ≥ 25 °C)	$\Delta P_{C}/\Delta T_{a}$		-1.5	mW/°C
	Junction temperature		Tj		125	°C
Common	Operating temperature		T_{opr}		-55 to 110	°C
	Storage temperature		T _{stg}		-55 to 125	°C
	Lead soldering temperature	(10 s)	T _{sol}		260	°C
	Total power dissipation		P _T		250	mW
	Total power dissipation derating	(T _a ≥ 25 °C)	$\Delta P_T / \Delta T_a$		-2.5	mW/°C
	Isolation voltage	(AC, 60 s, R.H. ≤ 60 %)	BV _S	(Note 2)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 0.1 ms, f = 100 Hz

Note 2: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

8. Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V_{F}		I _F = 10 mA	1.1	1.25	1.4	V
	Input reverse current	I _R		V _R = 5 V	_		10	μΑ
	Input capacitance	Ct		V = 0 V, f = 1 MHz	_	30	_	pF
Detector	Collector-emitter breakdown voltage	V _{(BR)CEO}		I _C = 0.1 mA	300			V
	Emitter-collector breakdown voltage	V _{(BR)ECO}		I _E = 0.1 mA	0.3			V
	Dark Current	I _{DARK}		V _{CE} = 200 V	_	0.002	0.2	μА
				V _{CE} = 200 V, T _a = 85 °C	_	_	20	
	Collector-emitter capacitance	C _{CE}		V = 0 V, f = 1 MHz	_	900		pF

9. Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	I _C /I _F		I _F = 1 mA, V _{CE} = 1 V	1000	6000	_	%
Saturated current transfer ratio	I _C /I _{F(sat)}		I _F = 10 mA, V _{CE} = 1 V	500	_	_	%
Collector-emitter saturation voltage	V _{CE(sat)}		I _C = 10 mA, I _F = 1 mA	_	_	1.0	V
			I _C = 100 mA, I _F = 10 mA	0.3	_	1.2	
OFF-state collector current	I _{C(off)}		V _F = 0.7 V, V _{CE} = 200 V			20	μА



10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		0.6		pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	5000	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

11. Switching Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r		V_{CC} = 10 V, I_{C} = 10 mA,	_	60	_	μS
Fall time	t _f		$R_L = 100 \Omega$	_	30	_	
Turn-on time	t _{on}			_	110	_	
Turn-off time	t _{off}			_	30	_	
Turn-on time	t _{on}		See Fig. 11.1.	_	2	_	
Storage time	ts		$R_L = 180 \ \Omega, \ V_{CC} = 10 \ V,$ $I_F = 16 \ mA$	_	25	_	
Turn-off time	t _{off}		115 - 10 11174	_	80	_	

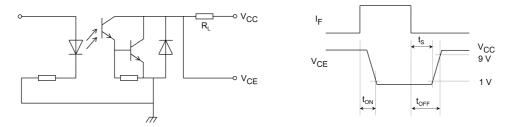


Fig. 11.1 Switching Time Test Circuit and Waveform



12. Characteristics Curves (Note)

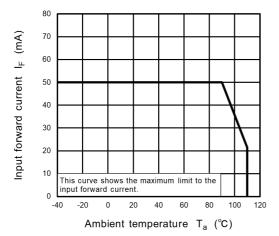


Fig. 12.1 I_F - T_a

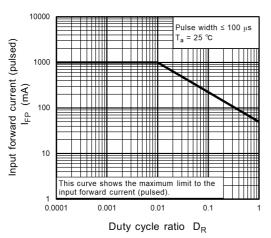


Fig. 12.3 I_{FP} - D_R

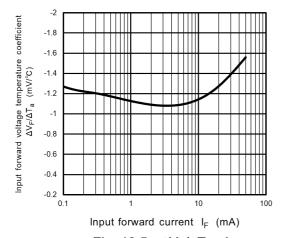


Fig. 12.5 $\Delta V_F/\Delta T_a - I_F$

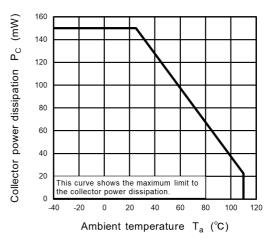


Fig. 12.2 P_C - T_a

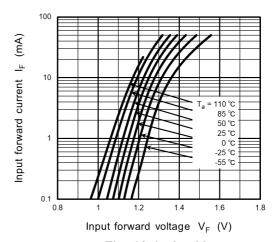


Fig. 12.4 I_F - V_F

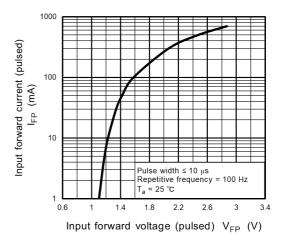


Fig. 12.6 I_{FP} - V_{FP}



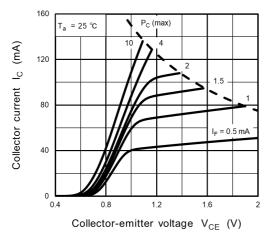


Fig. 12.7 I_C - V_{CE}

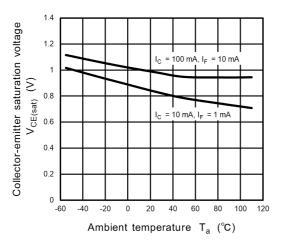


Fig. 12.9 V_{CE(sat)} - T_a

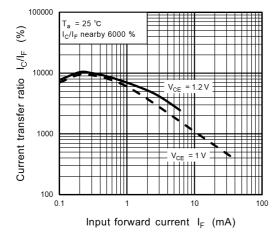


Fig. 12.11 I_C/I_F - I_F

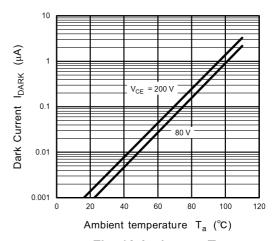


Fig. 12.8 IDARK - Ta

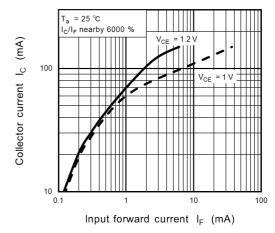


Fig. 12.10 I_C - I_F

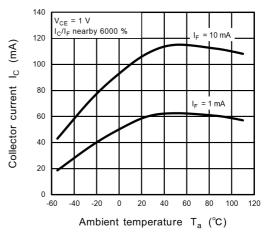
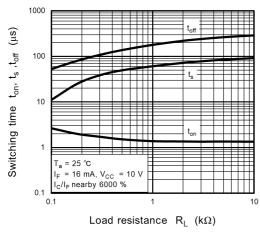


Fig. 12.12 I_C - T_a





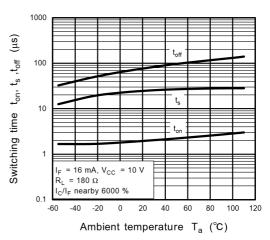


Fig. 12.13 Switching Time - RL

Fig. 12.14 Switching Time - Ta

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

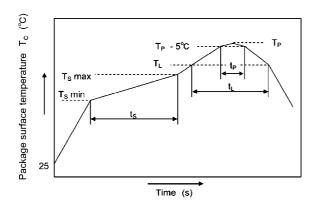
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	217		°C
Time above T _L	tL	60	150	s
Peak temperature	T _P		260	°C
Time during which T_c is between $(T_P - 5)$ and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 $^{\circ}\text{C}$ (package surface temperature) for 60 to 120 seconds.

Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 $^{\circ}$ C or within 3 seconds not exceeding 350 $^{\circ}$ C

Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the devices in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the devices in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.



14. Marking (Note)

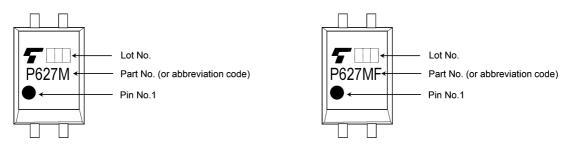


Fig. 14.1 Marking example of TLP627M

Fig. 14.2 Marking example of TLP627MF

Note: A different marking is used for photocouplers that have been qualified according to option (D4) of EN IEC 60747. See Fig.15.4 and Fig.15.5.



15. EN IEC 60747-5-5 Option (D4) Specification

• Part number: TLP627M, TLP627MF (Note 1)

• The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN IEC 60747.

Example: TLP627M(D4-TP1,E

D4: EN IEC 60747 option

TP1: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 2)

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP627M(D4-TP1,E \rightarrow TLP627M

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Description			Rating	Unit	
Application classification for rated mains voltage ≤ 600 Vrms for rated mains voltage ≤ 1000 Vrms			I-IV I-III	_	
Climatic classification			55 / 110 / 21	_	
Pollution degree			2	_	
	TLPxxxx type	1/1	890		
Maximum operating insulation voltage	TLPxxxxF type	VIORM	1140	Vpeak	
Input to output test voltage, Method A	TLPxxxx type	Vpr	1424	- Vpeak	
V_{pr} = 1.6 × VIORM, type and sample test t _p = 10 s, partial discharge < 5 pC	TLPxxxxF type		1824		
Input to output test voltage, Method B	TLPxxxx type	Vpr	1670	- Vpeak	
V_{pr} = 1.875 × VIORM, 100 % production test tp = 1 s, partial discharge < 5 pC	TLPxxxxF type		2140		
Highest permissible overvoltage (transient overvoltage, t _{pr} = 60 s)		VTR	8000	Vpeak	
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve) current (input current IF, Pso = 0) power (output or total power dissipation) temperature			400 700 150	mA mW °C	
Insulation resistance $ \begin{array}{c} \text{V}_{IO} = 500 \text{ V, T}_{a} = 25 \text{ °C} \\ \text{V}_{IO} = 500 \text{ V, T}_{a} = 100 \text{ °C} \\ \text{V}_{IO} = 500 \text{ V, T}_{a} = \text{T}_{s} \\ \end{array} $		Rsi	$\geq 10^{12}$ $\geq 10^{11}$ $\geq 10^{9}$	Ω	

Fig. 15.1 EN IEC 60747 Insulation Characteristics



		7.62 mm pitch TLPxxx type	10.16 mm pitch TLPxxxF type	
Minimum creepage distance	Cr	7.0 mm	8.0 mm	
Minimum clearance	CI	7.0 mm	8.0 mm	
Minimum insulation thickness	ti	0.4 mm		
Comparative tracking index	СТІ	500		

Fig. 15.2 Insulation Related Specifications (Note)

Note: If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. (e.g., at a standard distance between soldering eye centers of 7.5 mm). If this is not permissible, the user shall take suitable measures.

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 15.3 Marking on packing for EN IEC 60747

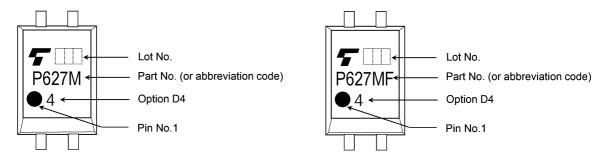
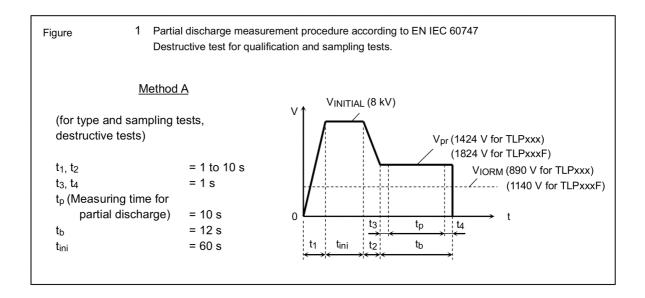
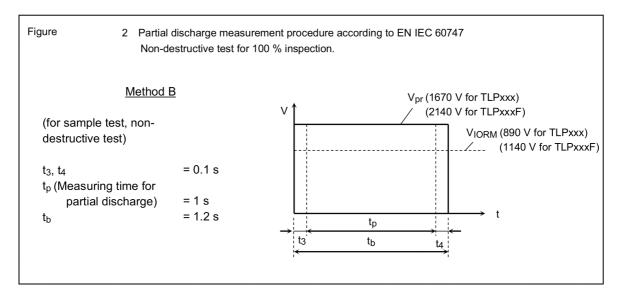


Fig. 15.4 Marking Example of TLP627M(Note) Fig. 15.5 Marking Example of TLP627MF(Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN IEC 60747.







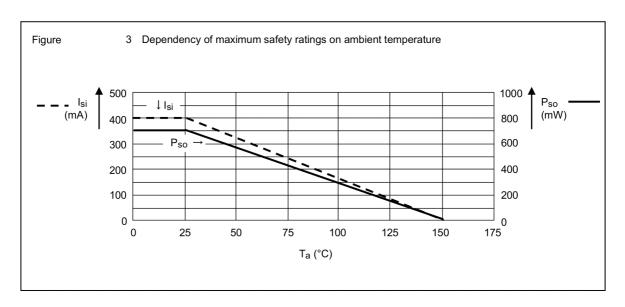
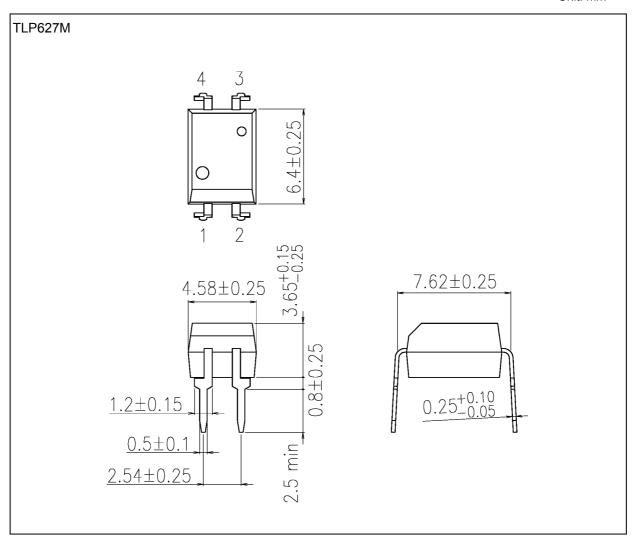


Fig. 15.6 Measurement Procedure



Unit: mm

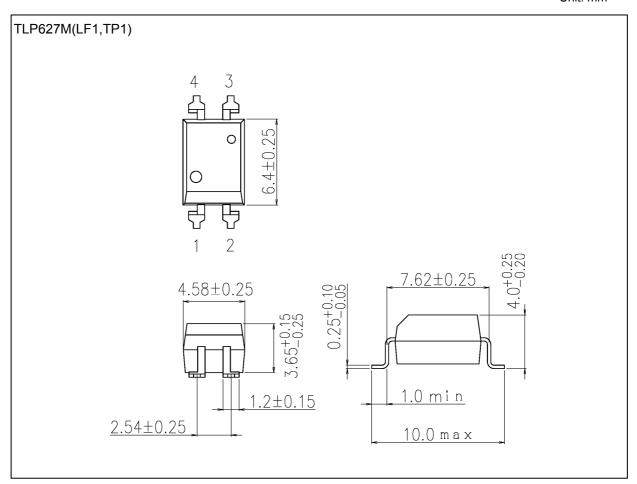


Weight: 0.24 g (typ.)

	Package Name(s)
TOSHIBA: 11-5B2S	



Unit: mm

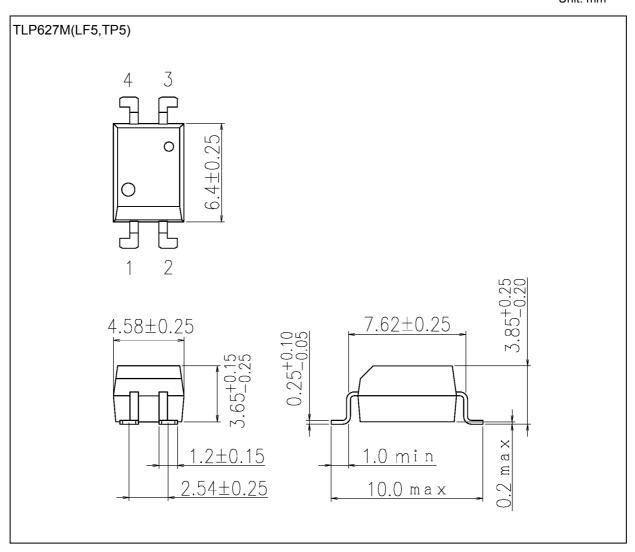


Weight: 0.24 g (typ.)

Р	Package Name(s)
TOSHIBA: 11-5B201S	



Unit: mm

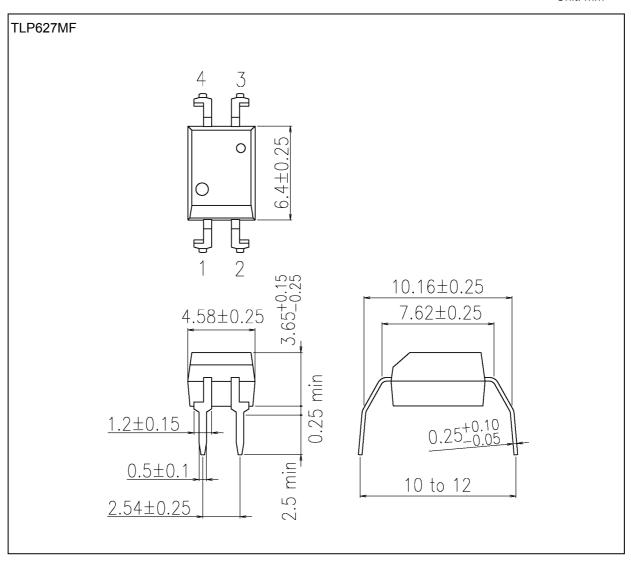


Weight: 0.24 g (typ.)

Package Name(s)	
TOSHIBA: 11-5B205S	



Unit: mm

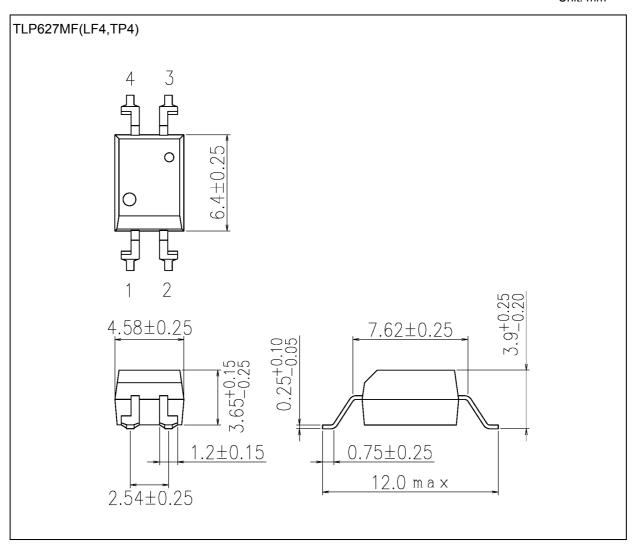


Weight: 0.24 g (typ.)

Package Name(s)
TOSHIBA: 11-5B202S



Unit: mm



Weight: 0.24 g (typ.)

F	Package Name(s)
TOSHIBA: 11-5B204S	



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- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
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